

# RF Power Field Effect Transistors

## N-Channel Enhancement-Mode Lateral MOSFETs

Designed for WiMAX base station applications with frequencies up to 3800 MHz. Suitable for WiMAX, WiBro, BWA, and OFDM multicarrier Class AB and Class C amplifier applications.

- Typical WiMAX Performance:  $V_{DD} = 30$  Volts,  $I_{DQ} = 450$  mA,  $P_{out} = 8$  Watts Avg.,  $f = 3400$ -3600 MHz, 802.16d, 64 QAM  $3/4$ , 4 bursts, 7 MHz Channel Bandwidth, Input Signal PAR = 9.5 dB @ 0.01% Probability on CCDF.  
Power Gain — 14 dB  
Drain Efficiency — 15.6%  
Device Output Signal PAR — 8.4 dB @ 0.01% Probability on CCDF  
ACPR @ 5.25 MHz Offset — -49 dBc in 0.5 MHz Channel Bandwidth
- Capable of Handling 10:1 VSWR, @ 32 Vdc, 3500 MHz, 40 Watts CW Peak Tuned Output Power
- $P_{out}$  @ 1 dB Compression Point  $\geq 40$  Watts CW

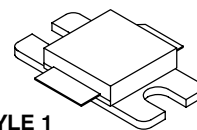
### Features

- Characterized with Series Equivalent Large-Signal Impedance Parameters
- Internally Matched for Ease of Use
- Integrated ESD Protection
- Greater Negative Gate-Source Voltage Range for Improved Class C Operation
- RoHS Compliant
- In Tape and Reel. R3 Suffix = 250 Units per 32 mm, 13 inch Reel.

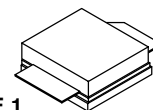
**MRF7S38040HR3**  
**MRF7S38040HSR3**

**3400-3600 MHz, 8 W AVG., 30 V**  
**WiMAX**  
**LATERAL N-CHANNEL**  
**RF POWER MOSFETs**

**CASE 465I-02, STYLE 1**  
**NI-400-240**  
**MRF7S38040HR3**



**CASE 465J-02, STYLE 1**  
**NI-400S-240**  
**MRF7S38040HSR3**



**Table 1. Maximum Ratings**

| Rating                               | Symbol    | Value        | Unit |
|--------------------------------------|-----------|--------------|------|
| Drain-Source Voltage                 | $V_{DS}$  | -0.5, +65    | Vdc  |
| Gate-Source Voltage                  | $V_{GS}$  | -6.0, +10    | Vdc  |
| Operating Voltage                    | $V_{DD}$  | 32, +0       | Vdc  |
| Storage Temperature Range            | $T_{stg}$ | - 65 to +150 | °C   |
| Case Operating Temperature           | $T_C$     | 150          | °C   |
| Operating Junction Temperature (1,2) | $T_J$     | 225          | °C   |

**Table 2. Thermal Characteristics**

| Characteristic                                                                                          | Symbol          | Value (2,3)  | Unit |
|---------------------------------------------------------------------------------------------------------|-----------------|--------------|------|
| Thermal Resistance, Junction to Case<br>Case Temperature 96°C, 39 W CW<br>Case Temperature 75°C, 8 W CW | $R_{\theta JC}$ | 0.78<br>0.83 | °C/W |

- Continuous use at maximum temperature will affect MTTF.
- MTTF calculator available at <http://www.freescale.com/rf>. Select Tools/Software/Application Software/Calculators to access the MTTF calculators by product.
- Refer to AN1955, *Thermal Measurement Methodology of RF Power Amplifiers*. Go to <http://www.freescale.com/rf>. Select Documentation/Application Notes - AN1955.

**Table 3. ESD Protection Characteristics**

| Test Methodology                      | Class        |
|---------------------------------------|--------------|
| Human Body Model (per JESD22-A114)    | 1C (Minimum) |
| Machine Model (per EIA/JESD22-A115)   | A (Minimum)  |
| Charge Device Model (per JESD22-C101) | IV (Minimum) |

**Table 4. Electrical Characteristics** ( $T_C = 25^\circ\text{C}$  unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

**Off Characteristics**

|                                                                                                   |           |   |   |    |                 |
|---------------------------------------------------------------------------------------------------|-----------|---|---|----|-----------------|
| Zero Gate Voltage Drain Leakage Current<br>( $V_{DS} = 65\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ ) | $I_{DSS}$ | — | — | 10 | $\mu\text{Adc}$ |
| Zero Gate Voltage Drain Leakage Current<br>( $V_{DS} = 28\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ ) | $I_{DSS}$ | — | — | 1  | $\mu\text{Adc}$ |
| Gate-Source Leakage Current<br>( $V_{GS} = 5\text{ Vdc}$ , $V_{DS} = 0\text{ Vdc}$ )              | $I_{GSS}$ | — | — | 1  | $\mu\text{Adc}$ |

**On Characteristics**

|                                                                                                               |              |     |      |     |     |
|---------------------------------------------------------------------------------------------------------------|--------------|-----|------|-----|-----|
| Gate Threshold Voltage<br>( $V_{DS} = 10\text{ Vdc}$ , $I_D = 124\text{ }\mu\text{Adc}$ )                     | $V_{GS(th)}$ | 1.2 | 2    | 2.7 | Vdc |
| Gate Quiescent Voltage<br>( $V_{DD} = 28\text{ Vdc}$ , $I_D = 450\text{ mAdc}$ , Measured in Functional Test) | $V_{GS(Q)}$  | 2   | 2.7  | 3.5 | Vdc |
| Drain-Source On-Voltage<br>( $V_{GS} = 10\text{ Vdc}$ , $I_D = 1.15\text{ Adc}$ )                             | $V_{DS(on)}$ | 0.1 | 0.21 | 0.3 | Vdc |

**Dynamic Characteristics <sup>(1)</sup>**

|                                                                                                                       |           |   |     |   |    |
|-----------------------------------------------------------------------------------------------------------------------|-----------|---|-----|---|----|
| Reverse Transfer Capacitance<br>( $V_{DS} = 28\text{ Vdc} \pm 30\text{ mV(rms)ac}$ @ 1 MHz, $V_{GS} = 0\text{ Vdc}$ ) | $C_{rss}$ | — | 0.4 | — | pF |
| Output Capacitance<br>( $V_{DS} = 28\text{ Vdc} \pm 30\text{ mV(rms)ac}$ @ 1 MHz, $V_{GS} = 0\text{ Vdc}$ )           | $C_{oss}$ | — | 229 | — | pF |
| Input Capacitance<br>( $V_{DS} = 28\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc} \pm 30\text{ mV(rms)ac}$ @ 1 MHz)            | $C_{iss}$ | — | 268 | — | pF |

**Functional Tests** (In Freescale Test Fixture, 50 ohm system)  $V_{DD} = 30\text{ Vdc}$ ,  $I_{DQ} = 450\text{ mA}$ ,  $P_{out} = 8\text{ W Avg.}$ ,  $f = 3400\text{ MHz}$  and  $f = 3600\text{ MHz}$ , WiMAX Signal, 802.16d, 7 MHz Channel Bandwidth, 64 QAM  $3/4$ , 4 Bursts, PAR = 9.5 dB @ 0.01% Probability on CCDF. ACPR measured in 0.5 MHz Channel Bandwidth @  $\pm 5.25\text{ MHz}$  Offset.

|                                                          |          |     |      |     |     |
|----------------------------------------------------------|----------|-----|------|-----|-----|
| Power Gain                                               | $G_{ps}$ | 12  | 14   | 16  | dB  |
| Drain Efficiency                                         | $\eta_D$ | 14  | 15.6 | 24  | %   |
| Output Peak-to-Average Ratio @ 0.01% Probability on CCDF | PAR      | 7.3 | 8.4  | —   | dB  |
| Adjacent Channel Power Ratio                             | ACPR     | —   | -49  | -46 | dBc |
| Input Return Loss                                        | IRL      | —   | -10  | -5  | dB  |

1. Part internally matched both on input and output.

(continued)

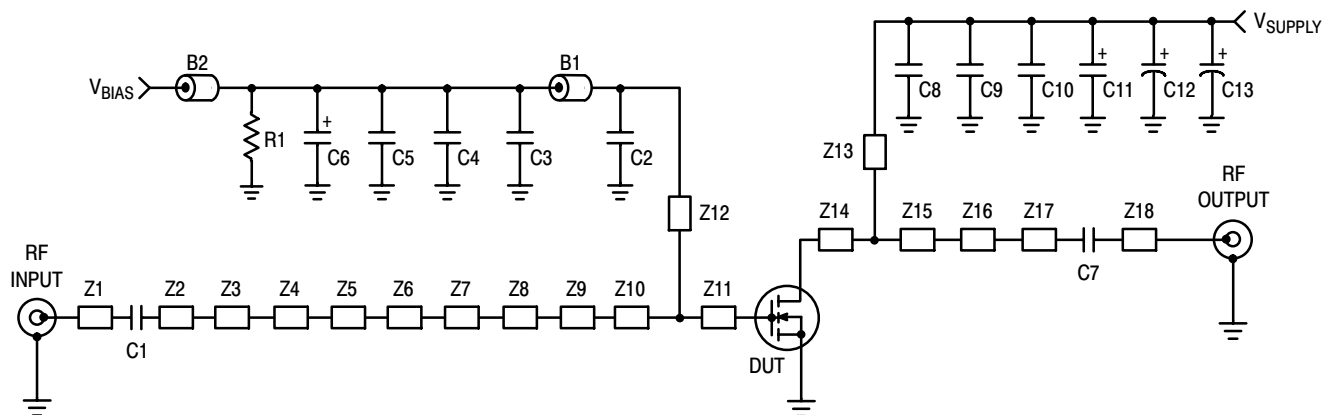
**Table 4. Electrical Characteristics** ( $T_C = 25^\circ\text{C}$  unless otherwise noted) (continued)

| Characteristic                                                                                                                                                                                                                                                                                                                                                | Symbol | Min | Typ                             | Max | Unit  |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------|-----|---------------------------------|-----|-------|
| <b>Typical Performances OFDM Signal</b> (In Freescale Test Fixture, 50 ohm system) $V_{DD} = 30\text{ Vdc}$ , $I_{DQ} = 450\text{ mA}$ , $P_{out} = 8\text{ W Avg.}$ ,<br>$f = 3400\text{ MHz}$ and $f = 3600\text{ MHz}$ , WiMAX Signal, OFDM Single-Carrier, 7 MHz Channel Bandwidth, 64 QAM $3/4$ , 4 Bursts, PAR = 9.5 dB @<br>0.01% Probability on CCDF. |        |     |                                 |     |       |
| Mask System Type G @ $P_{out} = 8\text{ W Avg.}$<br>Point B at 3.5 MHz Offset<br>Point C at 5 MHz Offset<br>Point D at 7.4 MHz Offset<br>Point E at 14 MHz Offset<br>Point F at 17.5 MHz Offset                                                                                                                                                               | Mask   | —   | -27<br>-38<br>-42<br>-60<br>-60 | —   | dBc   |
| Relative Constellation Error @ $P_{out} = 8\text{ W Avg.}$ <sup>(1)</sup>                                                                                                                                                                                                                                                                                     | RCE    | —   | -34                             | —   | dB    |
| Error Vector Magnitude <sup>(1)</sup><br>(Typical EVM Performance @ $P_{out} = 8\text{ W Avg.}$ with OFDM 802.16d<br>Signal Call)                                                                                                                                                                                                                             | EVM    | —   | 2.0                             | —   | % rms |

**Typical Performances** (In Freescale Test Fixture, 50 ohm system)  $V_{DD} = 30\text{ Vdc}$ ,  $I_{DQ} = 450\text{ mA}$ , 3400-3600 MHz Bandwidth

|                                                                                                                                                                                                                |                  |   |       |   |        |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------|---|-------|---|--------|
| Video Bandwidth @ 44 W PEP $P_{out}$ where IM3 = -30 dBc<br>(Tone Spacing from 100 kHz to VBW)<br>$\Delta\text{IMD3} = \text{IMD3 @ VBW frequency} - \text{IMD3 @ 100 kHz} < 1\text{ dBc}$ (both<br>sidebands) | VBW              | — | 30    | — | MHz    |
| Gain Flatness in 200 MHz Bandwidth @ $P_{out} = 8\text{ W Avg.}$                                                                                                                                               | $G_F$            | — | 0.87  | — | dB     |
| Average Deviation from Linear Phase in 200 MHz Bandwidth<br>@ $P_{out} = 40\text{ W CW}$                                                                                                                       | $\Phi$           | — | 1.62  | — | °      |
| Average Group Delay @ $P_{out} = 40\text{ W CW}$ , $f = 3500\text{ MHz}$                                                                                                                                       | Delay            | — | 1.65  | — | ns     |
| Part-to-Part Insertion Phase Variation @ $P_{out} = 40\text{ W CW}$ ,<br>$f = 3500\text{ MHz}$ , Six Sigma Window                                                                                              | $\Delta\Phi$     | — | 22.9  | — | °      |
| Gain Variation over Temperature<br>(-30°C to +85°C)                                                                                                                                                            | $\Delta G$       | — | 0.027 | — | dB/°C  |
| Output Power Variation over Temperature<br>(-30°C to +85°C)                                                                                                                                                    | $\Delta P_{1dB}$ | — | 0.121 | — | dBm/°C |

1.  $RCE = 20\text{Log}(EVM/100)$



|    |                                |          |                                                            |
|----|--------------------------------|----------|------------------------------------------------------------|
| Z1 | 0.822" x 0.084" Microstrip     | Z10, Z11 | 0.061" x 0.322" Microstrip                                 |
| Z2 | 0.454" x 0.386" Microstrip     | Z12      | 0.694" x 0.050" Microstrip                                 |
| Z3 | 0.950" x 0.220" Microstrip     | Z13      | 0.268" x 0.071" Microstrip                                 |
| Z4 | 0.023" x 0.358" Microstrip     | Z14      | 0.095" x 0.674" Microstrip                                 |
| Z5 | 0.400" x 0.379" Microstrip     | Z15      | 0.359" x 0.674" Microstrip                                 |
| Z6 | 0.230" x 0.358" Microstrip     | Z16      | 0.640" x 0.241" Microstrip                                 |
| Z7 | 0.100" x 0.358" x 0.104" Taper | Z17      | 0.410" x 0.084" Microstrip                                 |
| Z8 | 0.214" x 0.104" Microstrip     | Z18      | 0.726" x 0.084" Microstrip                                 |
| Z9 | 0.050" x 0.213" x 0.322" Taper | PCB      | Arlon CuClad 250GX-0300-55-22, 0.030", $\epsilon_r = 2.55$ |

**Figure 1. MRF7S38040HR3(HSR3) Test Circuit Schematic**

**Table 5. MRF7S38040HR3(HSR3) Test Circuit Component Designations and Values**

| Part           | Description                              | Part Number         | Manufacturer |
|----------------|------------------------------------------|---------------------|--------------|
| B1, B2         | Chip Ferrite Beads                       | 2508051107Y0        | Fair-Rite    |
| C1, C2, C7, C8 | 2.7 pF Chip Capacitors                   | ATC100B2R7BT500XT   | ATC          |
| C3, C9         | 36 pF Chip Capacitors                    | ATC100B360BT500XT   | ATC          |
| C4, C10        | 0.01 $\mu$ F, 100 V Chip Capacitors      | C1825C103J1RAC      | Kemet        |
| C5             | 1K pF Chip Capacitor                     | ATC100B102BT50XT    | ATC          |
| C6             | 10 $\mu$ F, 35 V Tantalum Capacitor      | T491C106K035AT      | Kemet        |
| C11            | 22 $\mu$ F, 35 V Tantalum Capacitor      | T491C226K035AT      | Kemet        |
| C12            | 470 $\mu$ F, 63 V Electrolytic Capacitor | EKME630ELL471MK25S  | Multicomp    |
| C13            | 100 $\mu$ F, 50 V Electrolytic Capacitor | MCHT101M1HB-1017-RH | Multicomp    |
| R1             | 180 K $\Omega$ , 1/4 W Chip Resistor     | CRCW12061803FKEA    | Vishay       |

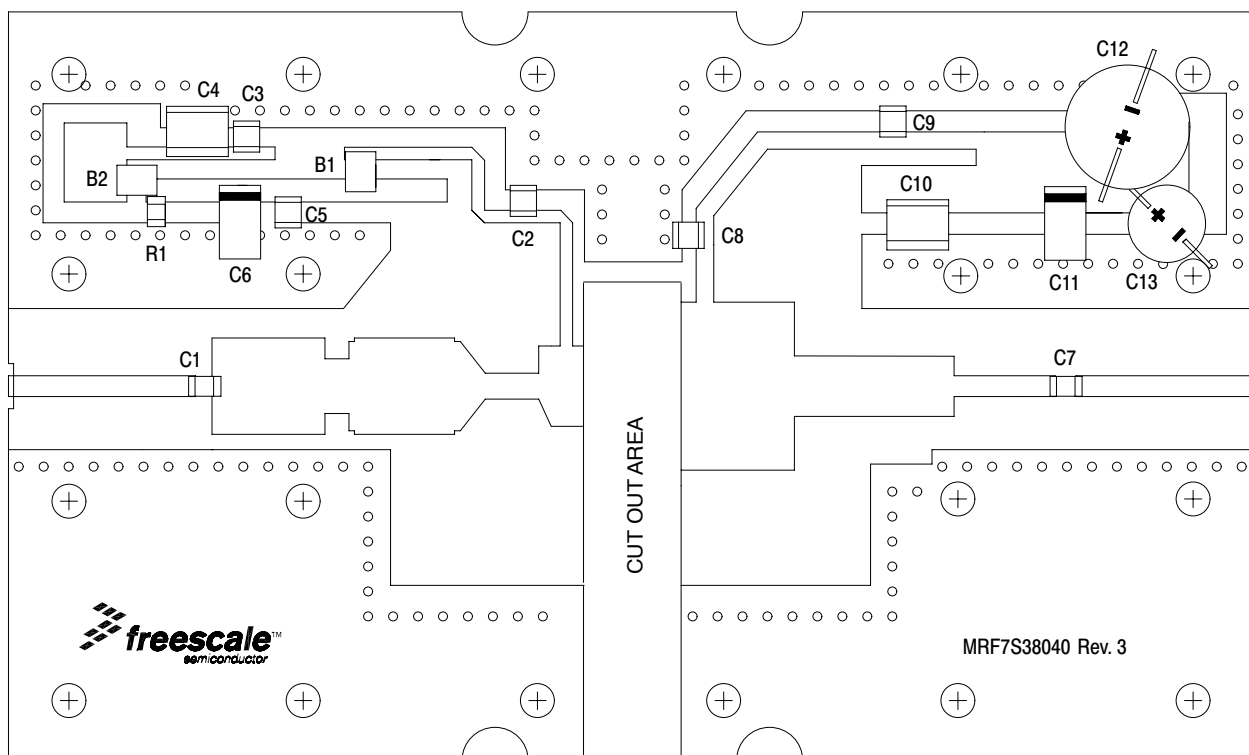


Figure 2. MRF7S38040HR3(HSR3) Test Circuit Component Layout

## TYPICAL CHARACTERISTICS

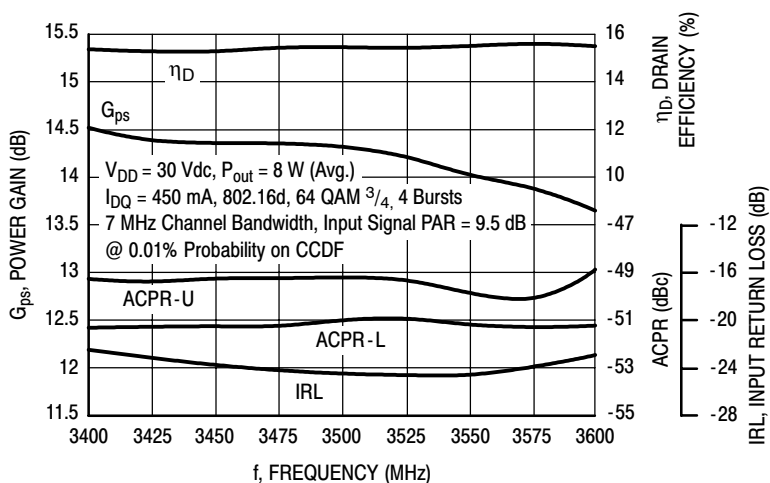


Figure 3. WiMAX Broadband Performance @  $P_{out} = 8$  Watts Avg.

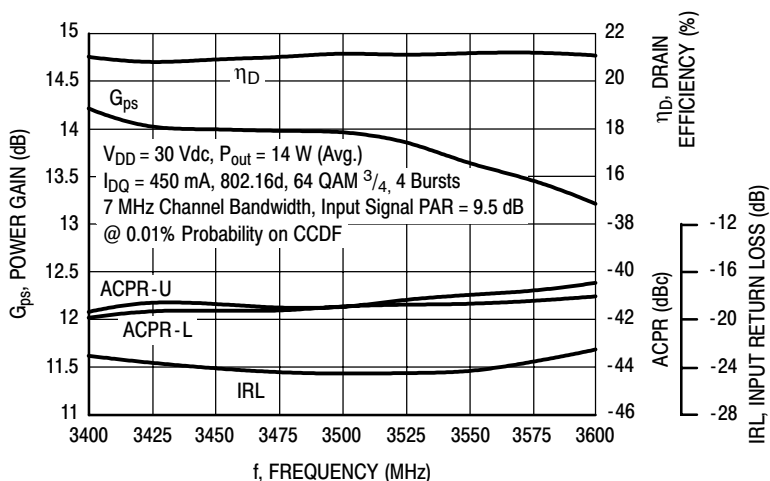


Figure 4. WiMAX Broadband Performance @  $P_{out} = 14$  Watts Avg.

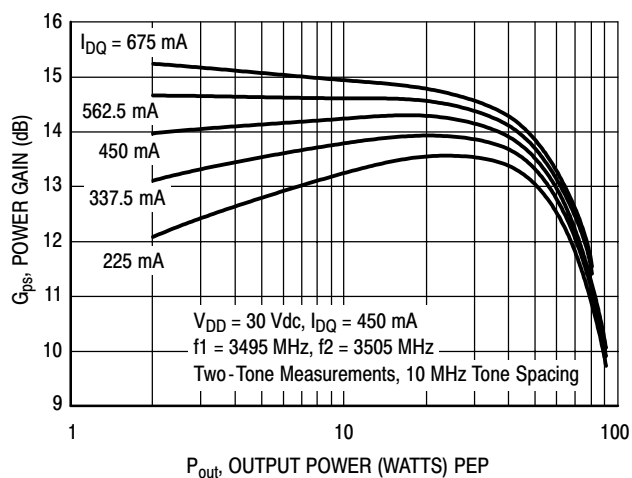


Figure 5. Two-Tone Power Gain versus Output Power

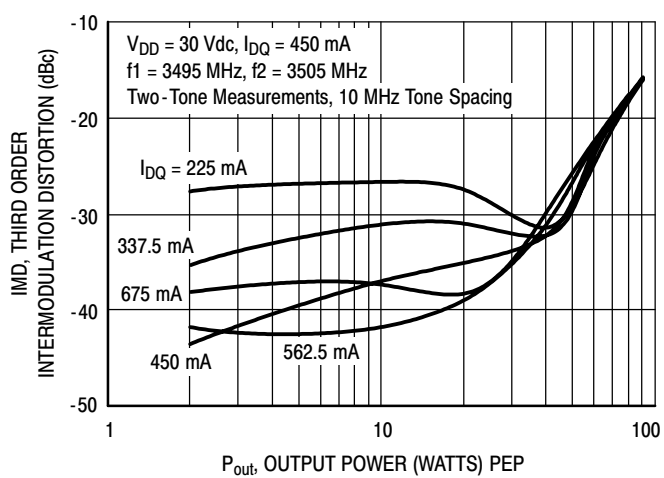
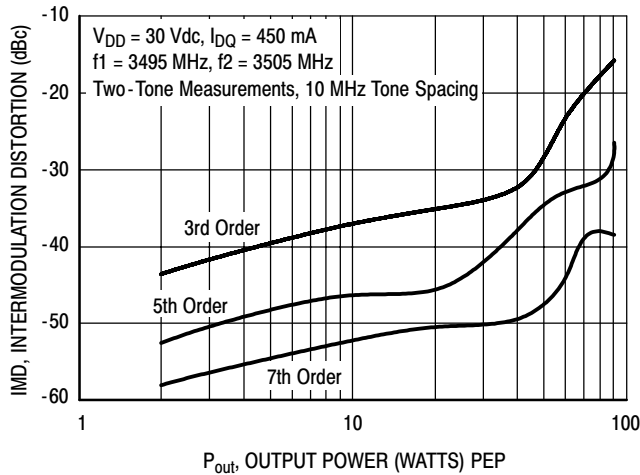
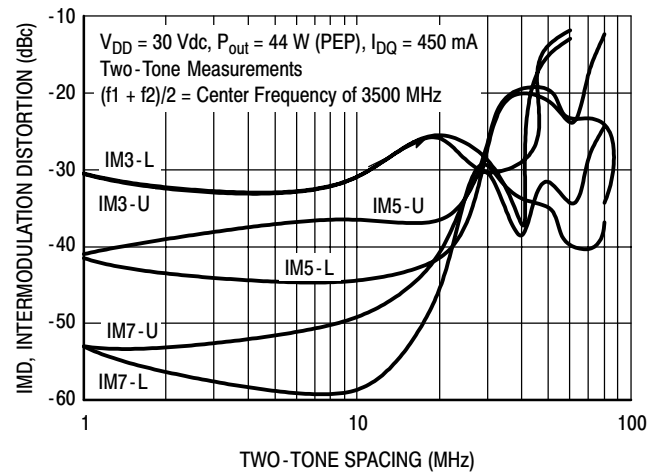


Figure 6. Third Order Intermodulation Distortion versus Output Power

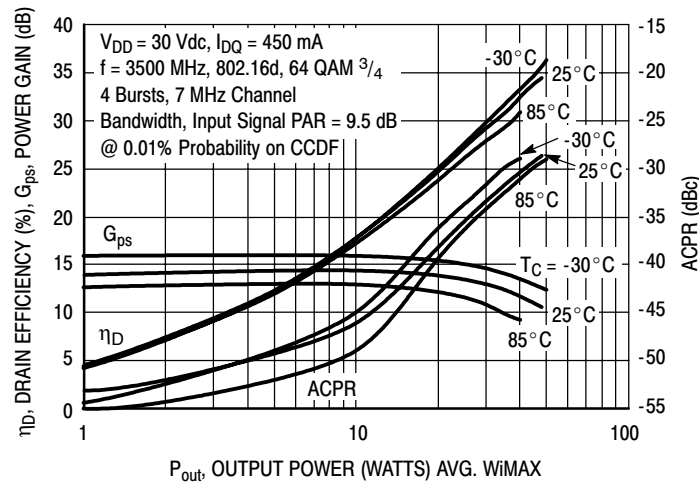
## TYPICAL CHARACTERISTICS



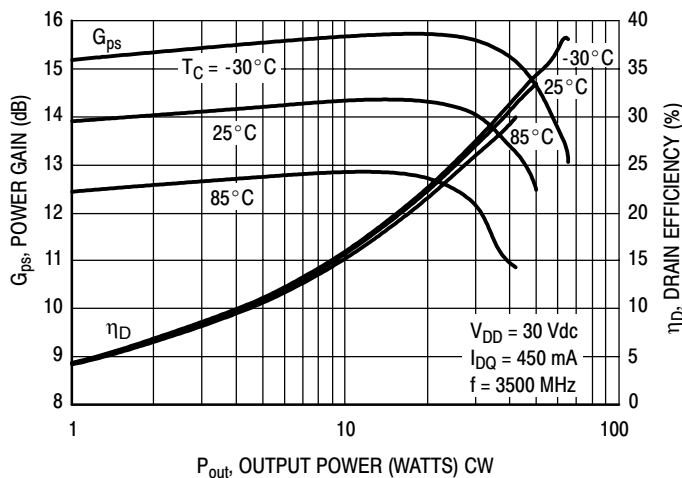
**Figure 7. Intermodulation Distortion Products versus Output Power**



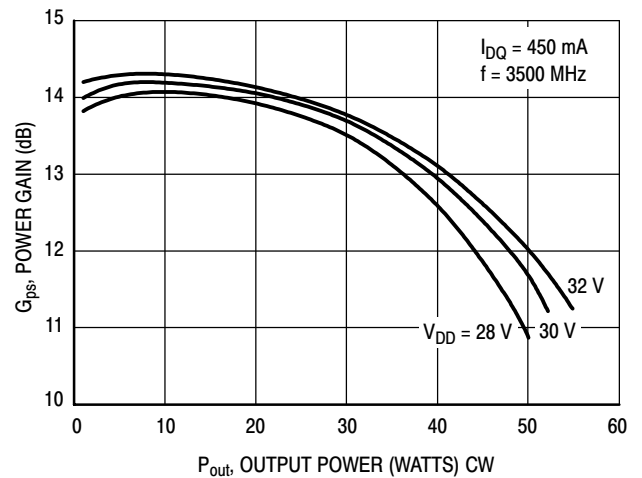
**Figure 8. Intermodulation Distortion Products versus Tone Spacing**



**Figure 9. WiMAX, ACPR, Power Gain and Drain Efficiency versus Output Power**

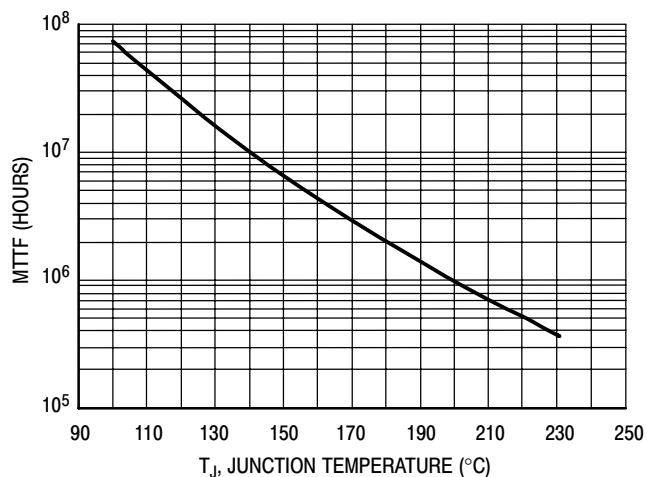


**Figure 10. Power Gain and Drain Efficiency versus CW Output Power**



**Figure 11. Power Gain versus Output Power**

## TYPICAL CHARACTERISTICS

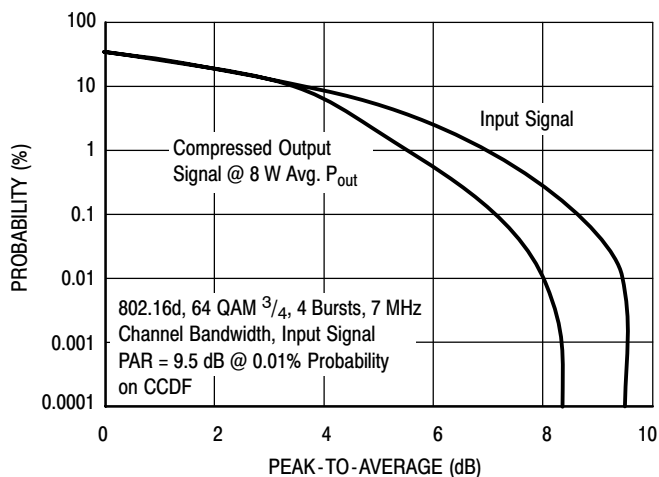


This above graph displays calculated MTTF in hours when the device is operated at  $V_{DD} = 30$  Vdc,  $P_{out} = 8$  W Avg., and  $\eta_D = 15.6\%$ .

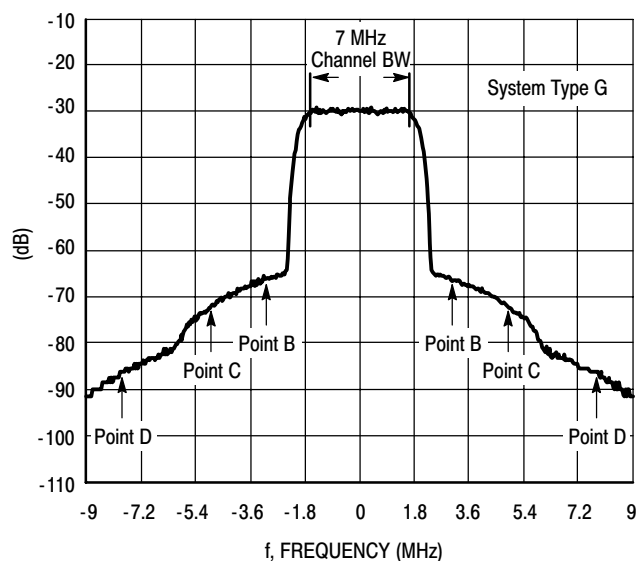
MTTF calculator available at <http://www.freescale.com/rf>. Select Tools/Software/Application Software/Calculators to access the MTTF calculators by product.

**Figure 12. MTTF versus Junction Temperature**

## WIMAX TEST SIGNAL

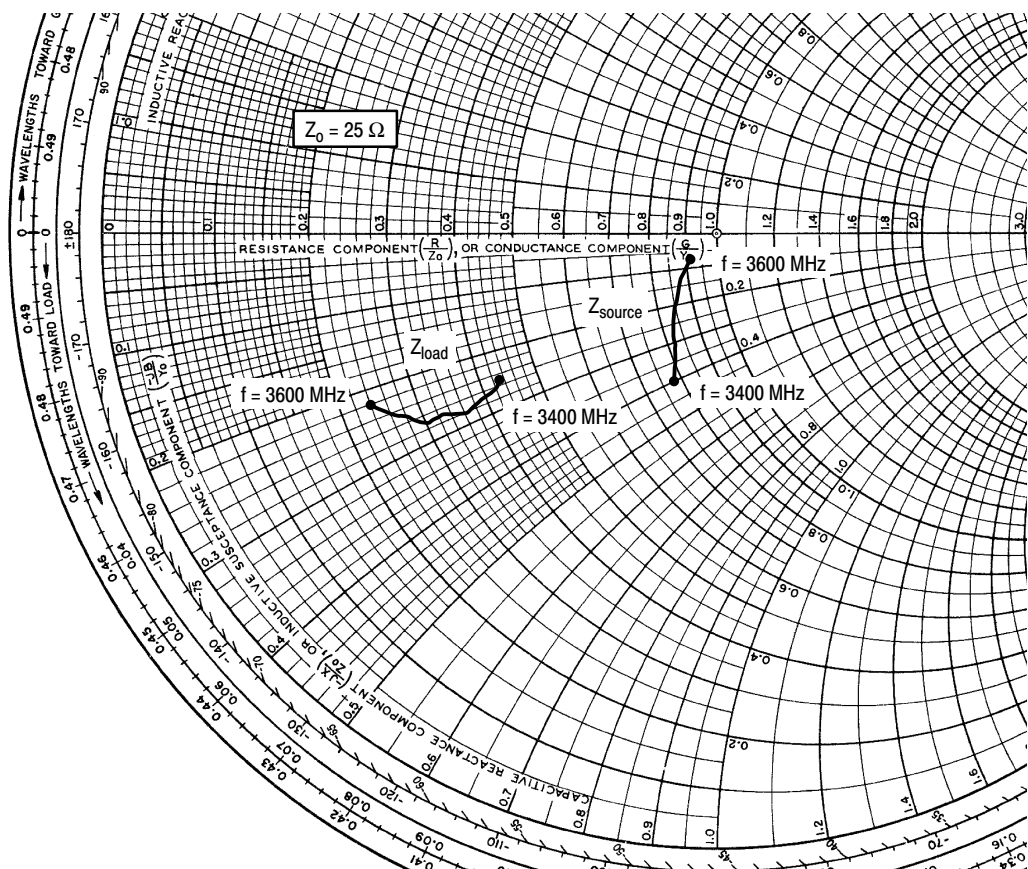


**Figure 13. OFDM 802.16d Test Signal**



**Figure 14. WiMAX Spectrum Mask Specifications**





$V_{DD} = 30 \text{ Vdc}$ ,  $I_{DQ} = 450 \text{ mA}$ ,  $P_{out} = 8 \text{ W Avg.}$

| f<br>MHz | $Z_{source}$<br>$\Omega$ | $Z_{load}$<br>$\Omega$ |
|----------|--------------------------|------------------------|
| 3400     | 19.57 - j9.98            | 10.66 - j6.30          |
| 3425     | 20.02 - j9.03            | 10.41 - j6.55          |
| 3450     | 20.33 - j8.18            | 9.85 - j6.83           |
| 3475     | 20.45 - j7.42            | 9.06 - j6.91           |
| 3500     | 20.78 - j6.65            | 8.30 - j6.84           |
| 3525     | 21.07 - j5.79            | 7.57 - j6.64           |
| 3550     | 21.45 - j4.55            | 6.91 - j6.31           |
| 3575     | 22.03 - j3.26            | 6.39 - j5.92           |
| 3600     | 22.73 - j2.06            | 5.97 - j5.48           |

$Z_{source}$  = Test circuit impedance as measured from gate to ground.

$Z_{load}$  = Test circuit impedance as measured from drain to ground.

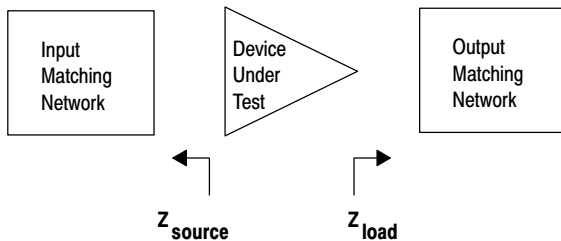
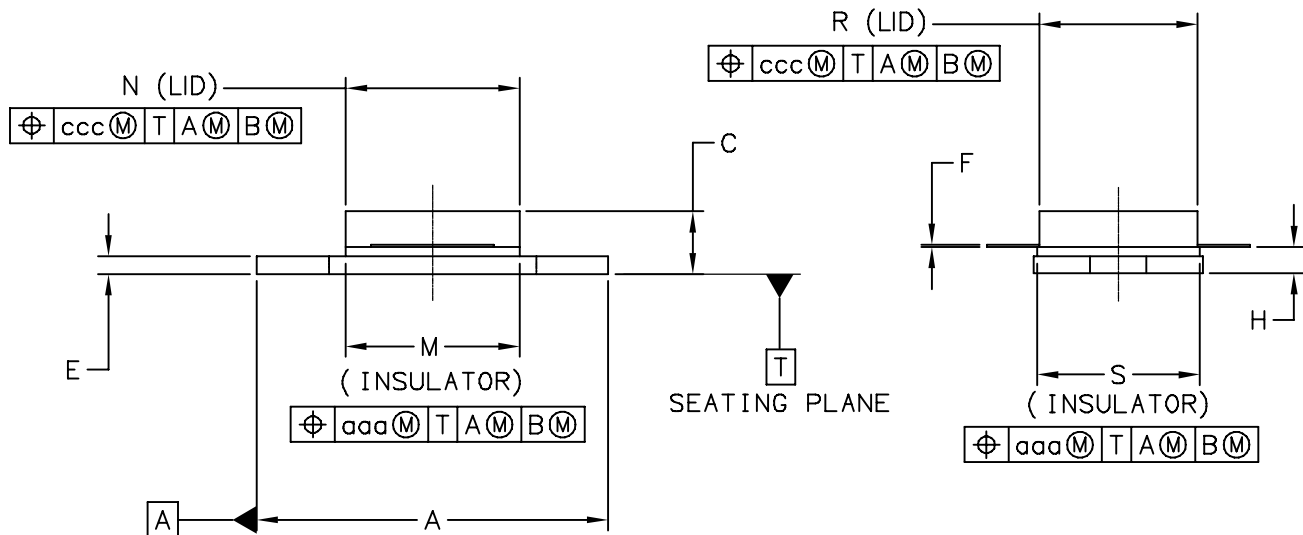
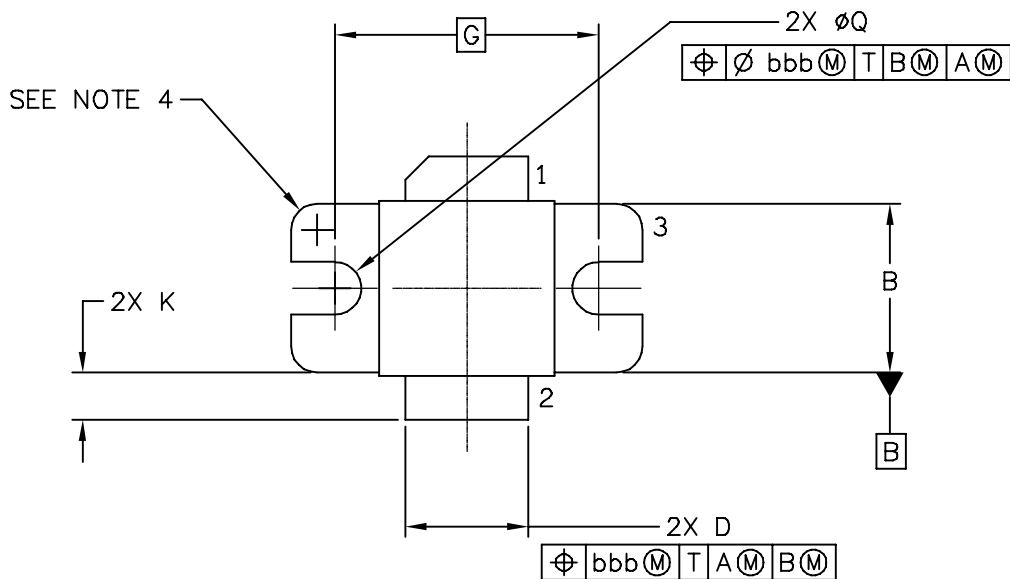


Figure 15. Series Equivalent Source and Load Impedance

# PACKAGE DIMENSIONS



|                                                         |  |                    |                          |                            |             |
|---------------------------------------------------------|--|--------------------|--------------------------|----------------------------|-------------|
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| TITLE:<br><br>NI-400-240                                |  |                    | DOCUMENT NO: 98ASA10730D |                            | REV: B      |
|                                                         |  |                    | CASE NUMBER: 465I-02     |                            | 09 MAY 2006 |
|                                                         |  |                    | STANDARD: NON-JEDEC      |                            |             |

# NOTES:

1. CONTROLLING DIMENSION: INCH
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
3. DIMENSION H IS MEASURED .030 (0.762) AWAY FROM PACKAGE BODY.
4. INFORMATION ONLY:  
CORNER BREAK (4X) TO BE .060±.005 (1.52±0.13) RADIUS OR  
.06±.005 (1.52±0.13) × 45° CHAMFER.

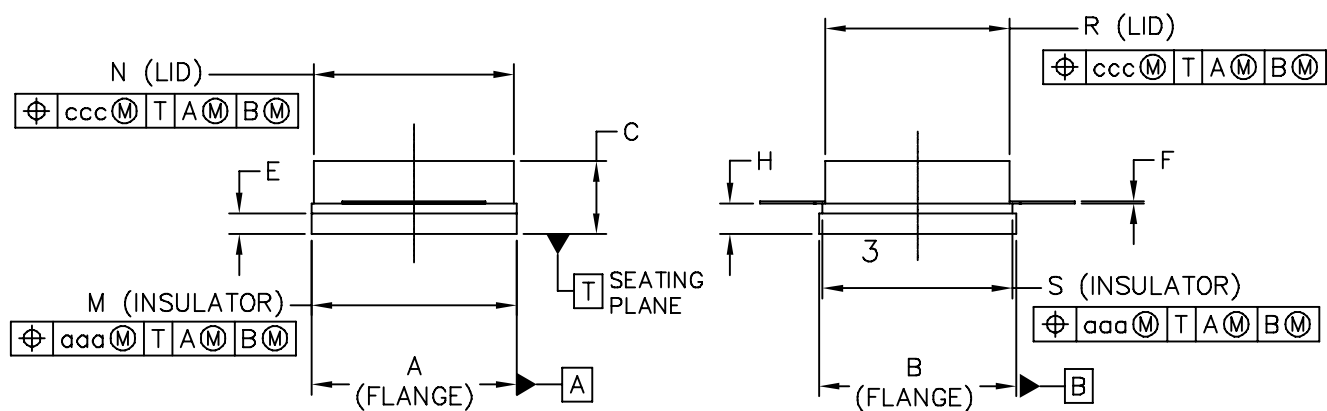
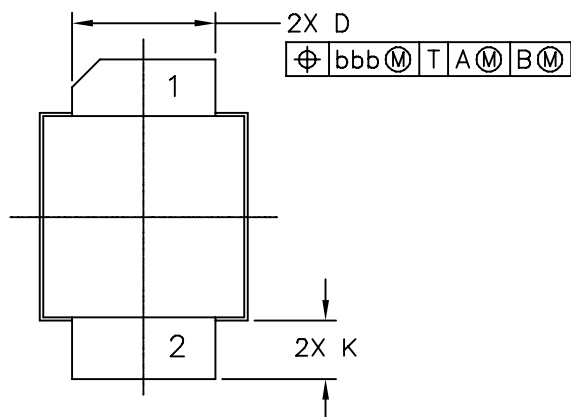
## STYLE 1

PIN 1: DRAIN  
PIN 2: GATE  
PIN 3: SOURCE

## STYLE 2

PIN 1: GATE  
PIN 2: DRAIN  
PIN 3: SOURCE

| DIM                                                     | INCH     |       | MILLIMETER         |       | DIM                      | INCH                       |      | MILLIMETER  |      |
|---------------------------------------------------------|----------|-------|--------------------|-------|--------------------------|----------------------------|------|-------------|------|
|                                                         | MIN      | MAX   | MIN                | MAX   |                          | MIN                        | MAX  | MIN         | MAX  |
| A                                                       | .795     | .805  | 20.19              | 20.44 | R                        | .355                       | .365 | 9.02        | 9.27 |
| B                                                       | .380     | .390  | 9.65               | 9.91  | S                        | .365                       | .375 | 9.27        | 9.53 |
| C                                                       | .125     | .163  | 3.17               | 4.14  |                          |                            |      |             |      |
| D                                                       | .275     | .285  | 6.98               | 7.24  | aaa                      | .005                       |      | 0.127       |      |
| E                                                       | .035     | .045  | 0.89               | 1.14  | bbb                      | .010                       |      | 0.254       |      |
| F                                                       | .004     | .006  | 0.10               | 0.15  | ccc                      | .015                       |      | 0.381       |      |
| G                                                       | .600 BSC |       | 15.24 BSC          |       |                          |                            |      |             |      |
| H                                                       | .057     | .067  | 1.45               | 1.70  |                          |                            |      |             |      |
| K                                                       | .0995    | .1295 | 2.53               | 3.29  |                          |                            |      |             |      |
| M                                                       | .395     | .405  | 10.03              | 10.29 |                          |                            |      |             |      |
| N                                                       | .385     | .395  | 9.78               | 10.03 |                          |                            |      |             |      |
| Q                                                       | Ø.120    | Ø.130 | Ø3.05              | Ø3.30 |                          |                            |      |             |      |
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| TITLE:<br><br>NI-400-240                                |          |       |                    |       | DOCUMENT NO: 98ASA10730D |                            |      | REV: B      |      |
|                                                         |          |       |                    |       | CASE NUMBER: 465I-02     |                            |      | 09 MAY 2006 |      |
|                                                         |          |       |                    |       | STANDARD: NON-JEDEC      |                            |      |             |      |



|                                                         |  |                          |                            |             |
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| TITLE:<br><br>NI-400S-240                               |  | DOCUMENT NO: 98ASA10732D |                            | REV: A      |
|                                                         |  | CASE NUMBER: 465J-02     |                            | 09 MAY 2006 |
|                                                         |  | STANDARD: NON-JEDEC      |                            |             |

NOTES:

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2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
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STYLE 1:

- PIN 1 - DRAIN
- 2 - GATE
- 3 - SOURCE

STYLE 2:

- PIN 1 - GATE
- 2 - DRAIN
- 3 - SOURCE

| DIM                                                     | INCH  |       | MILLIMETER         |       | DIM                      | INCH                       |     | MILLIMETER  |     |
|---------------------------------------------------------|-------|-------|--------------------|-------|--------------------------|----------------------------|-----|-------------|-----|
|                                                         | MIN   | MAX   | MIN                | MAX   |                          | MIN                        | MAX | MIN         | MAX |
| A                                                       | .395  | .405  | 10.03              | 10.29 | aaa                      | .005                       |     | 0.127       |     |
| B                                                       | .380  | .390  | 9.65               | 9.91  | bbb                      | .010                       |     | 0.254       |     |
| C                                                       | .125  | .163  | 3.18               | 4.14  | ccc                      | .015                       |     | 0.381       |     |
| D                                                       | .275  | .285  | 6.98               | 7.24  |                          |                            |     |             |     |
| E                                                       | .035  | .045  | 0.89               | 1.14  |                          |                            |     |             |     |
| F                                                       | .004  | .006  | 0.10               | 0.15  |                          |                            |     |             |     |
| H                                                       | .057  | .067  | 1.45               | 1.70  |                          |                            |     |             |     |
| K                                                       | .0995 | .1295 | 2.53               | 3.29  |                          |                            |     |             |     |
| M                                                       | .395  | .405  | 10.03              | 10.29 |                          |                            |     |             |     |
| N                                                       | .385  | .395  | 9.78               | 10.03 |                          |                            |     |             |     |
| R                                                       | .355  | .365  | 9.02               | 9.27  |                          |                            |     |             |     |
| S                                                       | .365  | .375  | 9.27               | 9.53  |                          |                            |     |             |     |
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| TITLE:<br><br>NI-400S-240                               |       |       |                    |       | DOCUMENT NO: 98ASA10732D |                            |     | REV: A      |     |
|                                                         |       |       |                    |       | CASE NUMBER: 465J-02     |                            |     | 09 MAY 2006 |     |
|                                                         |       |       |                    |       | STANDARD: NON-JEDEC      |                            |     |             |     |

## PRODUCT DOCUMENTATION

Refer to the following documents to aid your design process.

### Application Notes

- AN1955: Thermal Measurement Methodology of RF Power Amplifiers

### Engineering Bulletins

- EB212: Using Data Sheet Impedances for RF LDMOS Devices

## REVISION HISTORY

The following table summarizes revisions to this document.

| Revision | Date      | Description                                                                       |
|----------|-----------|-----------------------------------------------------------------------------------|
| 0        | Aug. 2007 | <ul style="list-style-type: none"> <li>• Initial Release of Data Sheet</li> </ul> |

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